Product data sheet

1. Product profile

1.1 General description

Planar passivated sensitive gate four quadrant triac in a SOT223 (SC-73) surface-mountable plastic package intended for applications requiring direct interfacing to logic level ICs and low power gate drivers.

1.2 Features and benefits

- Direct interfacing to logic level ICs
- Direct interfacing to low power gate drive circuits
- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate in four quadrants
- Surface-mountable package
- Triggering in all four quadrants

1.3 Applications

- General purpose low power motor control
- Home appliances

- Industrial process control
- Low power AC Fan controllers

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25$ °C; $t_p = 20$ ms; see Figure 4; see Figure 5	-	-	8	Α
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{sp} \le 105 ^{\circ}\text{C}$; see <u>Figure 3</u> ; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	-	1	Α



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Table 1. Quick reference data ...continued

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	ecteristics					
0.	gate trigger current	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 9}}{}$	-	-	10	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2+ \text{ G-;} $ $T_j = 25 \text{ °C; see } \frac{\text{Figure 9}}{\text{ Figure 9}}$	-	-	10	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2\text{- G-;}$ $T_j = 25 \text{ °C; see } \frac{\text{Figure 9}}{}$	-	-	10	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2\text{- }G+;$ $T_j = 25 \text{ °C; see } \frac{\text{Figure 9}}{}$	-	-	10	mA

2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T1	main terminal 1		N.1
2	T2	main terminal 2	4	T2—T1
3	G	gate		`G sym051
4	T2	main terminal 2	1 2 3	
			SOT223 (SOT223)	

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
Z0109MN	SOT223	plastic surface-mounted package with increased heatsink; 4 leads	SOT223

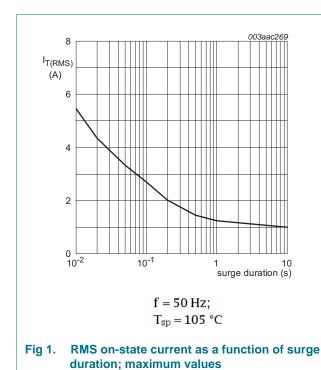
4Q Triac

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{sp} \le 105 ^{\circ}\text{C}$; see <u>Figure 3</u> ; see <u>Figure 1</u> ; see <u>Figure 2</u>	-	1	Α
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; see <u>Figure 4</u> ; see <u>Figure 5</u>	-	8	Α
		full sine wave; $T_{j(init)} = 25$ °C; $t_p = 16.7$ ms	-	8.5	Α
I ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	0.32	A ² s
dl _T /dt	rate of rise of on-state current	I_T = 1 A; I_G = 20 mA; dI_G/dt = 0.1 A/ μ s; T2+ G+	-	50	A/µs
		$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 0.1 \text{ A/}\mu\text{s}$; $T2+$ $G-$	-	50	A/µs
		$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 0.1 \text{ A/}\mu\text{s}$; T2- G-	-	50	A/µs
		$I_T = 1 \text{ A}$; $I_G = 20 \text{ mA}$; $dI_G/dt = 0.1 \text{ A/}\mu\text{s}$; T2- G+	-	20	A/µs
I _{GM}	peak gate current		-	1	Α
P_{GM}	peak gate power		-	2	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



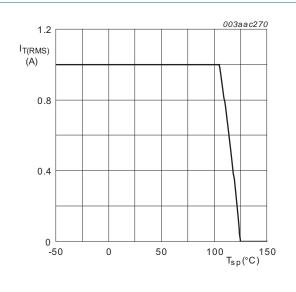
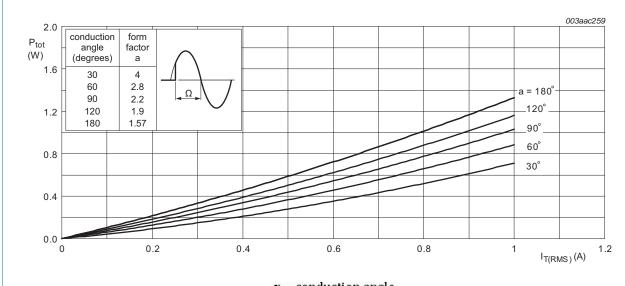


Fig 2. RMS on-state current as a function of solder point temperature; maximum values

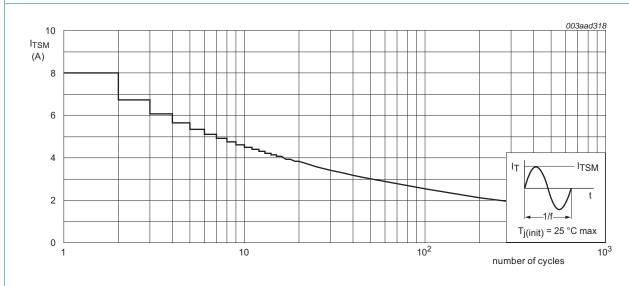
Z0109MN

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 $\alpha=$ conduction angle

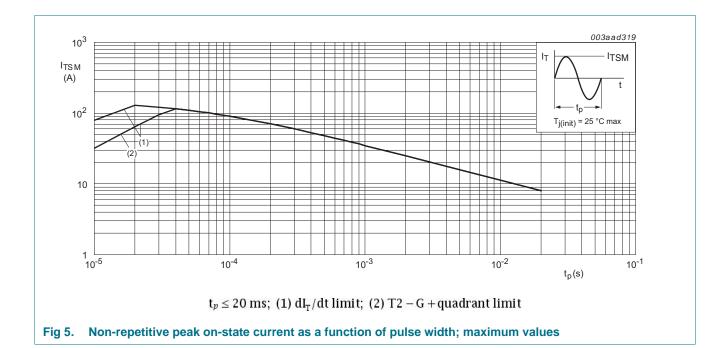
Fig 3. Total power dissipation as a function of RMS on-state current; maximum values



f = 50 Hz

Fig 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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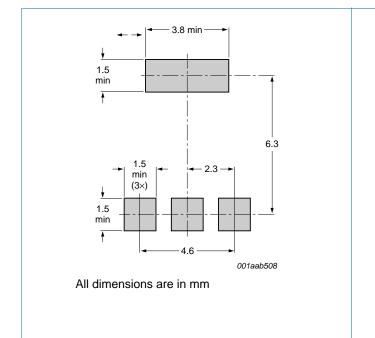


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5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	full cycle; see Figure 8	-	-	15	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	full cycle; printed circuit board mounted; minimum footprint; see Figure 6	-	156	-	K/W
		full cycle; printed circuit board mounted; pad area; see Figure 7	-	70	-	K/W



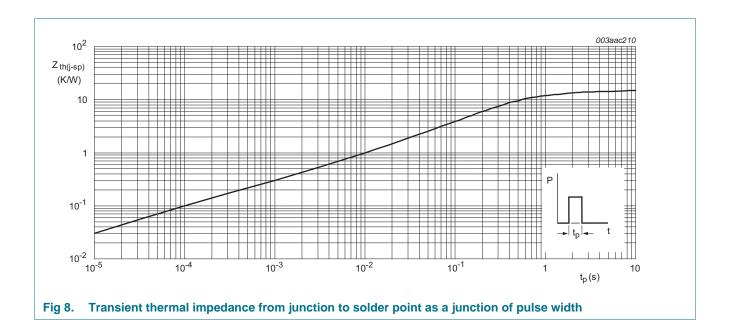
All dimensions are in mm

Printed circuit board:

FR4 epoxy glass (1.6 mm thick), copper laminate (35 um thick)

Fig 6. Minimum footprint SOT223

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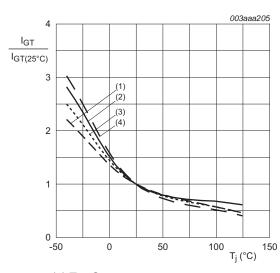
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6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + G+;$ $T_j = 25 \text{ °C; see } \frac{\text{Figure 9}}{\text{ or } 100 \text{ cm}}$	-	-	10	mA
		$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ G-;$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 9}}{}$	-	-	10	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; T2- G-;}$ $T_j = 25 \text{ °C; see } \frac{\text{Figure 9}}{\text{Figure 9}}$	-	-	10	mA
		$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2\text{- }G\text{+;} $ $T_j = 25 \text{ °C; see } \frac{\text{Figure 9}}{}$	-	-	10	mA
L	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G+; T_j = 25 °C; see Figure 10$	-	-	15	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G-;$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure } 10}{\text{ Colored}}$	-	-	25	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure } 10}{\text{ Figure } 10}$	-	-	15	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G+};$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure } 10}{\text{ Figure } 10}$	-	-	15	mΑ
l _H	holding current	$V_D = 12 \text{ V; } T_j = 25 \text{ °C; see } \frac{\text{Figure 11}}{\text{ or } T_j}$	-	-	10	mΑ
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; see <u>Figure 12</u>	-	1.3	1.6	V
V _{GT}	gate trigger voltage	$V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T_j = 25 \text{ °C;}$ see Figure 13	-	-	1.3	V
		$V_D = 600 \text{ V}; I_T = 0.1 \text{ A}; T_j = 125 \text{ °C};$ see Figure 13	0.2	-	-	V
Ь	off-state current	$V_D = 600 \text{ V}; T_j = 125 ^{\circ}\text{C}$	-	-	0.5	mΑ
Dynamic ch	naracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T_j = 110 °C; gate open circuit; exponential waveform; see Figure 14	50	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; T_j = 110 \text{ °C};$ $dI_{com}/dt = 0.44 \text{ A/ms}; \text{ gate open circuit}$	2	-	-	V/µs

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- (1) T2- G+
- (2) T2- G-
- (3) T2+ G-
- (4) T2+ G+

Fig 9. Normalized gate trigger current as a function of junction temperature

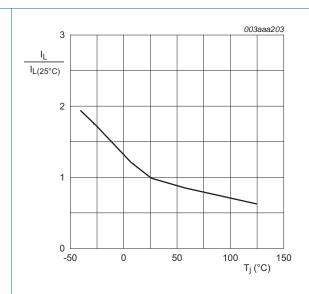


Fig 10. Normalized latching current as a function of junction temperature

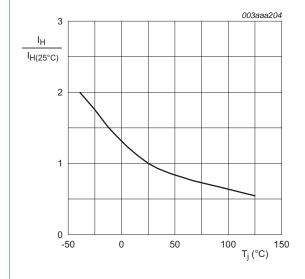
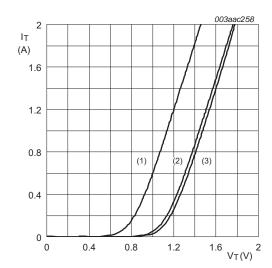


Fig 11. Normalized holding current as a function of junction temperature



 $V_0 = 1.13 \text{ V}$

 $R_s = 0.31 \Omega$

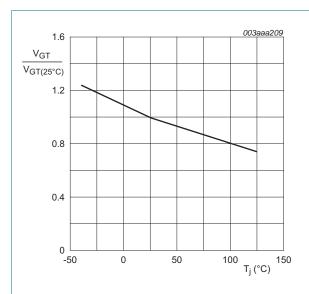
(1) T_i = 125 °C; typical values

(2) T_i = 125 °C; maximum values

(3) T_i = 25 °C; maximum values

Fig 12. On-state current as a function of on-state voltage

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junction temperature

Fig 13. Normalized gate trigger voltage as a function of Fig

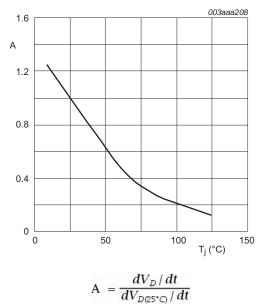


Fig 14. Normalized critical rate of rise of off-state voltage as a function of junction temperature; typical values

7. Package outline

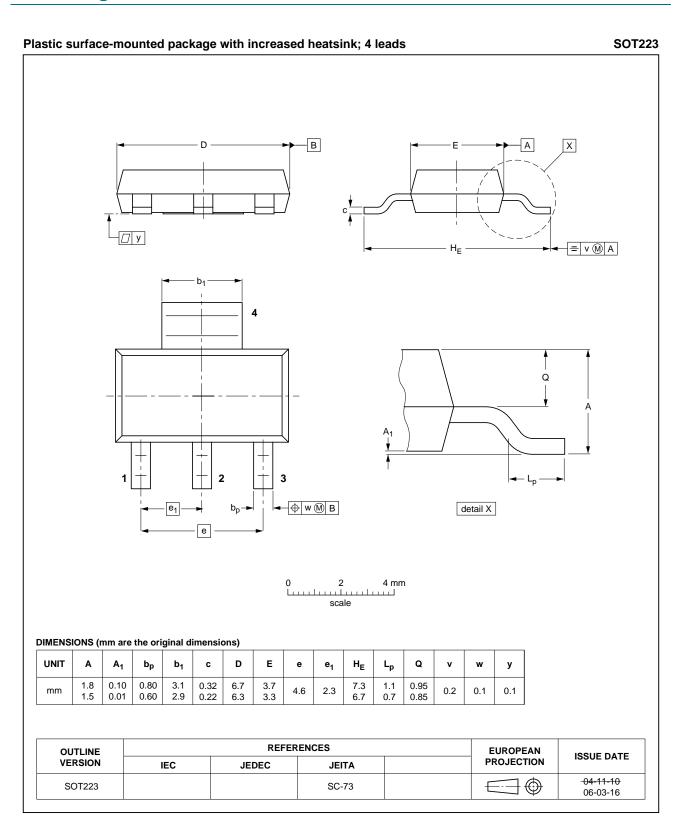


Fig 15. Package outline SOT223 (SOT223)

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NXP Semiconductors Z0109MN
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8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
Z0109MN v.5	20110322	Product data sheet	-	Z0109MN v.4
Modifications:	 Various chang 	es to content.		
Z0109MN v.4	20100906	Product data sheet	-	Z0109MN v.3

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9. Legal information

9.1 Data sheet status

Document status [1] [2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
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Z0109MN NXP Semiconductors 4Q Triac

11. Contents

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